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APPLICANT

Chia Gee WANG et al.

FILING DATE

GROUP

April 14, 2004

2811

2818

REFERENCE DESIGNATION

U.S. PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	FILING DATE IF APPROPRIATE
ah	AA	6,376,337	04/02	Wang et al.	
ah	AB	6,294,802	09/01	Unozawa	
ah	AC	6,355,951	03/02	Hattori	
ah	AD	6,479,836	11/02	Suzuki et al.	
ah	AE	6,452,206	09/02	Harman et al.	
ah	AF	6,537,911	03/03	Ko et al.	
ah	AG	4,261,771	04/1981	Dingle et al.	
	AH				
	AI				

FOREIGN PATENT DOCUMENTS

		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION	
					YES	NO
	AJ					
	AK					
	AL					
	AM					

OTHER ART (Including Author, Title, Date, Pertinent Dates, Etc.)

ah	AN	Tsu, R. "Phenomena in silicon nanostructure devices", <i>Applied Physics A</i> (2000), 71: 391-402
ah	AO	Tsu, Raphael et al. "Quantum Confinement in Silicon", <u>Proceedings of the Fourth International Symposium on Quantum Confinement: Nanoscale Materials, Devices, and Systems</u> , Volume 97-11, Cahay, M. et al. Editors. New Jersey: The Electrochemical Society, Inc. 341-351
ah	AP	Ding, Jinli and Raphael Tsu. "The determination of activation energy in quantum wells", <i>Appl. Phys. Lett.</i> (1997), 71(15): 2124-2126
ah	AQ	Seo, Yong-Jin and Raphael Tsu. "Electronic and Optical Characteristics of Multilayer Nanocrystalline Silicon/Adsorbed Oxygen Superlattice", <i>Jpn. J. Appl. Phys.</i> (2001), 40: 4799-4801
ah	AR	Seo, Yong-Jin et al. "Transport through a nine period silicon/oxygen superlattice", <i>Applied Physics Letters</i> (2001), 79(6): 788-790

EXAMINER

DATE CONSIDERED

EXAMINER:

Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.